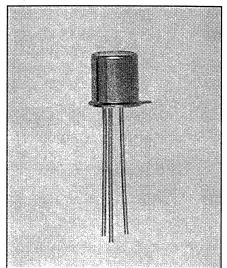


NPN Silicon Photodarlington Type OP830WSL



Features

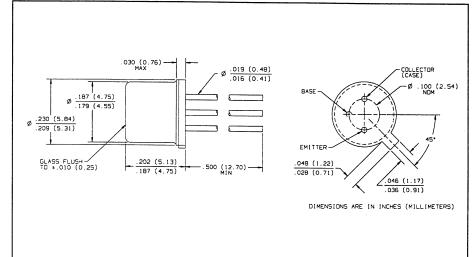
- · Wide receiving angle
- Enhanced temperature range
- Excellent thermal characteristics
- TO-18 hermetically sealed package
- Mechanically and spectrally matched • to the OP130W and OP231W series of infrared emitting diodes

Description

The OP830WSL consists of an NPN silicon photodarlington mounted in a hermetically sealed package. The wide receiving angle provides relatively even reception over a large area. Photodarlington devices are normally used in applications where light signal levels are low and more current gain is needed than is possible with phototransistors. TO-18 packages offer high power dissipation and superior hostile environment operation.

Replaces

OP830W and K9030 series



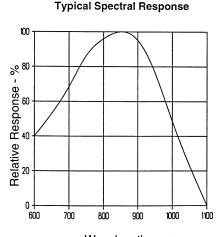
Absolute Maximum Ratings (T_A = 25^o C unless otherwise noted)

Collector-Emitter Voltage 15 V Emitter-Collector Voltage 5 V Continous Collector Current 50 mA Storage Temperature Range -65° C to +150° C Operating Temperature Range -55° C to +125° C Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 sec. with soldering iron] 260° C ⁽¹⁾
Iron]

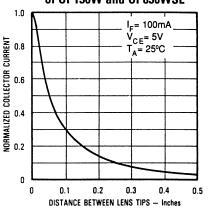
(1) RMA flux is recommended. Duration can be extended to 10 sec. max. when flow soldering. (2) Derate linearly 2.5 mW/° C above 25° C.
(3) Junction temperature maintained at 25° C.

(4) Light source is an unfiltered tungsten bulb operating at CT = 2870 K or equivalent infrared source.

Typical Performance Curves



Coupling Characteristics of OP130W and OP830WSL



Wavelength - nm

Optek Technology, Inc.

1215 W. Crosby Road

Carrollton, Texas 75006

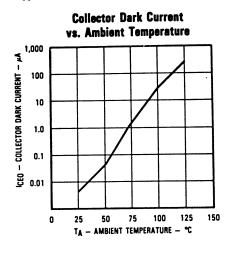
(972) 323-2200

OP830WSL

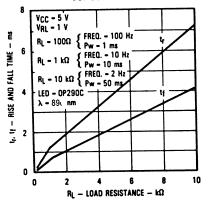
SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	
	On-State Collector Current	4			mA	$V_{CE} = 5 \text{ V}, \text{ E}_{e} = 0.5 \text{ mW/cm}^{2(4)}$
	Collector Dark Current			1.0	μA	V _{CE} = 10 V
	Collector-Emitter Breakdown Voltage	15			V	I _C = 100 μA
(=,===	Emitter-Collector Breakdown Voltage	5.0			V	I _E = 100 μA
(2.1)===	Collector-Emitter Saturation Voltage			1.20	V	$I_{C} = 1.0 \text{ mA}, E_{e} = 0.5 \text{ mW/cm}^{2(4)}$

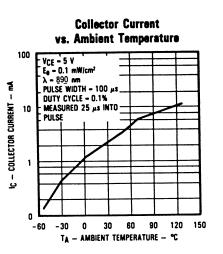
Electrical Characteristics ($T_A = 25^{\circ}$ C unless otherwise noted)

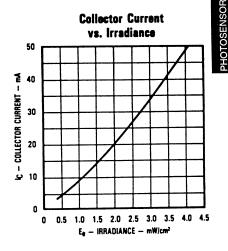
Typical Performance Curves



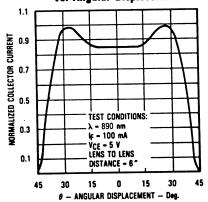
Rise and Fall Time vs. Load Resistance



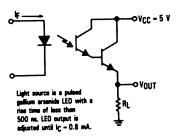




Normalized Collector Current vs. Angular Displacement







Optek reserves the right to make changes at any time in order to improve design and to supply the best product possible. Optek Technology, Inc. 1215 W. Crosby Road Carrollton, Texas 75006 (972)323-2200 Fax (972)323-2396